FCX605U

NPN Silicon High Voltage Darlington Transistor

Features

• Low Saturation Voltage

1 2 3

1.Base 2.Collector 3.Emitter SOT-89 Plastic Package

Application

- Various driving functions, Lamps, Motors, Relays and solenoids
- High output current switches

Absolute Maximum Ratings(T_a = 25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Collector Base Voltage	V_{CBO}	140	V
Collector Emitter Voltage	V _{CEO}	120	V
Emitter Base Voltage	V _{EBO}	10	V
Collector Current	I _C	1	Α
Peak Collector Current, Pulsed	I _{CM}	4	Α
Power Dissipation	P _D	1 ¹⁾ 2.8 ²⁾	W
Operating Junction Temperature Range	T _j	- 55 to + 150	°C
Storage Temperature Range	T _{stg}	- 55 to + 150	$^{\circ}$

Thermal Characteristics

Parameter	Symbol	Max.	Unit
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	125 ¹⁾ 45 ²⁾	°C/W

¹⁾ Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.



²⁾ Device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate in still air.

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Characteristics at T_a = 25°C unless otherwise specified

Parameter	Symbol	Min.	Тур.	Max.	Unit
DC Current Gain at V_{CE} = 5 V, I_C = 50 mA at V_{CE} = 5 V, I_C = 500 mA at V_{CE} = 5 V, I_C = 1 A at V_{CE} = 5 V, I_C = 2 A	h _{FE} h _{FE} h _{FE}	2000 5000 2000 500	- - - -	- 100000 -	
Collector Base Cutoff Current at $V_{CB} = 10 \text{ V}$	I _{CBO}	-	-	100	nA
Emitter Base Cutoff Current at V _{EB} = 8 V	I _{EBO}	-	-	100	nA
Collector Emitter Breakdown Voltage at $I_C = 10 \text{ mA}$	V _{(BR)CEO}	120	-	-	V
Collector Base Breakdown Voltage at I _C = 100 μA	V _{(BR)CBO}	140	-	-	V
Emitter Base Breakdown Voltage at I _E = 100 μA	V _{(BR)EBO}	10	-	-	V
Collector Emitter Saturation Voltage at I_C = 250 mA, I_B = 0.25 mA at I_C = 1 A, I_B = 1 mA	V _{CE(sat)}			1 1.5	٧
Base Emitter Saturation Voltage at $I_C = 1 A$, $I_B = 1 mA$	$V_{BE(sat)}$	-	-	1.8	V
Base Emitter Turn-on Voltage at $V_{CE} = 5 \text{ V}$, $I_C = 1 \text{ A}$	V _{BE(on)}	-	-	1.7	V
Gain Bandwidth Product at $V_{CE} = 10 \text{ V}$, $I_{C} = 100 \text{ mA}$, $f = 20 \text{ MHz}$	f⊤	150	-	-	MHz
Input Capacitance at $V_{CB} = 500 \text{ mV}$, $f = 1 \text{ MHz}$	C _{ibo}	-	90	-	pF
Output Capacitance at V _{CB} = 10 V, f = 1 MHz	C _{obo}	-	15	-	pF
Turn-on Time at V_{CE} = 10 V, I_C = 500 mA, I_{B1} = I_{B2} = 0.5 mA	t _(on)	-	0.5	-	μs
Turn-off Time at $V_{CE} = 10 \text{ V}$, $I_{C} = 500 \text{ mA}$, $I_{B1} = I_{B2} = 0.5 \text{ mA}$	t _(off)	-	1.6	-	μs

Electrical Characteristics Curves

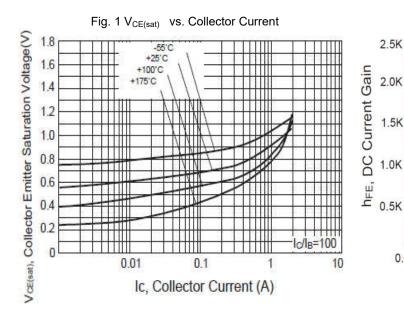


Fig. 2 DC Current Gain vs. Collector Current

Fig. 3 V_{BE(sat)} vs. Collector Current

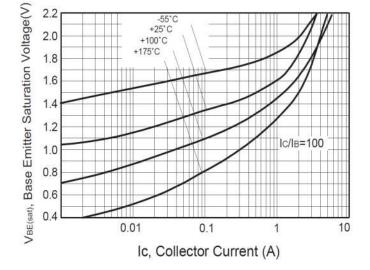


Fig. 4 Collector Current vs. V_{BE}

0.1

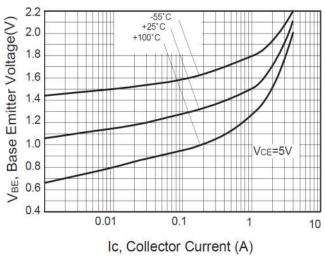
Ic, Collector Current (A)

1

10

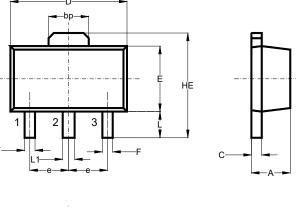
0.01

0.001



Package Outline (Dimensions in mm)

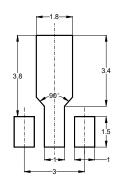
SOT-89





	Unit	Α	bp	С	D	Е	F	HE	е	L	L1
	mm	1.6	1.60	0.5	4.6	2.6	0.45	4.25	1.5	1.05	0.51
		1.4	1.50	0.3	4.4	2.4	0.35	3.75	typ.	0.95	0.41

Recommended Soldering Footprint



Packing information

1 doking information								
Package	Tape Width (mm)	Pitch		Ree	el Size	B B I B I : 0 : 11		
		mm	inch	mm	inch	Per Reel Packing Quantity		
007.00	40	0 : 0 4	0.045 + 0.004	178	7	1,000		
SOT-89	12	8 ± 0.1	0.315 ± 0.004	330	13	4,000		

Marking information

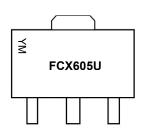
" FCX605U " = Part No.

"YM" = Date Code Marking

"Y" = Year

"M" = Month

Font type: Arial



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